

ELECTRICAL CHARACTERISTICS (T_{case} = 25°C unless otherwise stated)

| Parameter | Test Conditions | Min. | Typ. | Max. | Unit |
|--|---|------|------|------|------|
| B _V DSS Drain–Source Breakdown Voltage | V _{GS} = 0 I _D = 10mA | 40 | | | V |
| I _D SS Zero Gate Voltage Drain Current | V _{DS} = 12.5V V _{GS} = 0 | | | 8 | mA |
| I _G SS Gate Leakage Current | V _{GS} = 20V V _{DS} = 0 | | | 8 | μA |
| V _{GS(th)} Gate Threshold Voltage* | I _D = 10mA V _{DS} = V _{GS} | 0.5 | | 7 | V |
| g _{fs} Forward Transconductance* | V _{DS} = 10V I _D = 1.6A | 1.44 | | | S |
| G _{PS} Common Source Power Gain | P _O = 20W | 10 | | | dB |
| η Drain Efficiency | V _{DS} = 12.5V I _{DQ} = 1.6A | 40 | | | % |
| V _{SWR} Load Mismatch Tolerance | f = 500MHz | 20:1 | | | — |
| C _{iss} Input Capacitance | V _{DS} = 12.5V V _{GS} = -5V f = 1MHz | | | 96 | pF |
| C _{oss} Output Capacitance | V _{DS} = 12.5V V _{GS} = 0 f = 1MHz | | | 80 | pF |
| C _{rss} Reverse Transfer Capacitance | V _{DS} = 12.5V V _{GS} = 0 f = 1MHz | | | 8 | pF |

* Pulse Test: Pulse Duration = 300 μs , Duty Cycle ≤ 2%

HAZARDOUS MATERIAL WARNING

The ceramic portion of the device between leads and metal flange is beryllium oxide. Beryllium oxide dust is highly toxic and care must be taken during handling and mounting to avoid damage to this area.

THESE DEVICES MUST NEVER BE THROWN AWAY WITH GENERAL INDUSTRIAL OR DOMESTIC WASTE.

THERMAL DATA

| | | |
|-----------------------|------------------------------------|----------------|
| R _{THj-case} | Thermal Resistance Junction – Case | Max. 2.5°C / W |
|-----------------------|------------------------------------|----------------|

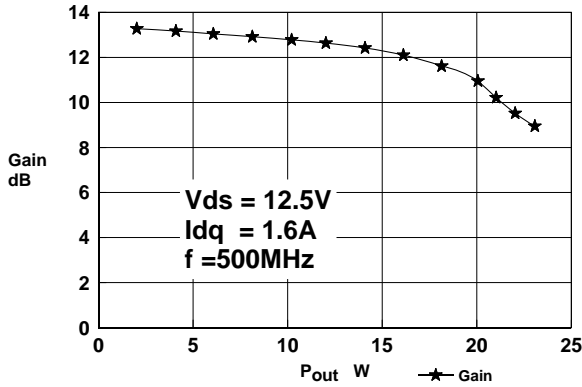


Figure 1 – Gain vs. Power Output.

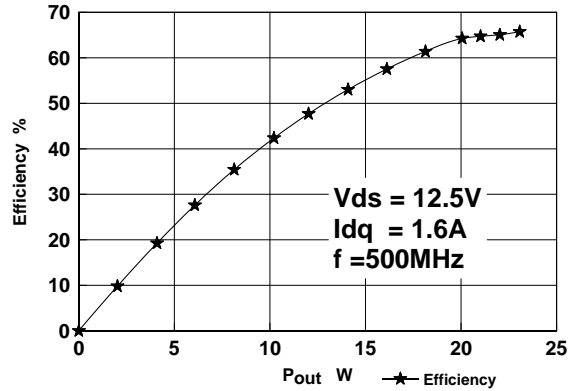


Figure 2 – Efficiency vs. Power Output.

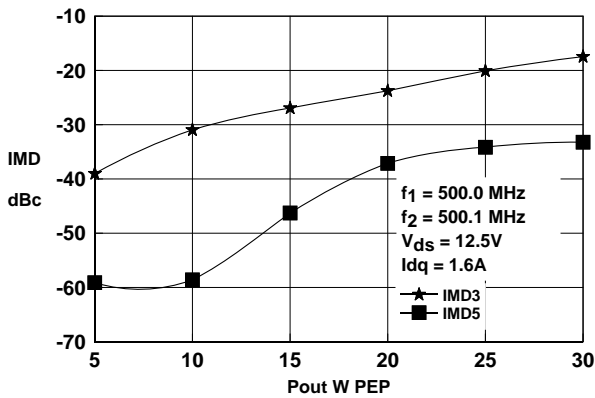


Figure 3 – IMD vs. Power Output.

D2218UK OPTIMUM SOURCE AND LOAD IMPEDANCE

| Frequency MHz | Z_S Ω | Z_L Ω |
|------------------|-------------------|-------------------|
| 500MHz | $1.4 + j1.1$ | $2.4 - j0.4$ |

Typical S Parameters

! $V_{DS} = 12.5V, I_{DQ} = 0.8A$
MHz S M A R 50

| !Freq MHz | S11 | | S21 | | S12 | | S22 | |
|--------------|------|------|------|-----|-------|-----|------|------|
| | mag | ang | mag | ang | mag | ang | mag | ang |
| 100 | 0.82 | -160 | 9.92 | 72 | 0.018 | -12 | 0.7 | -155 |
| 200 | 0.88 | -169 | 3.92 | 50 | 0.011 | -16 | 0.81 | -162 |
| 300 | 0.91 | -175 | 2.29 | 40 | 0.006 | 11 | 0.87 | -169 |
| 400 | 0.93 | -179 | 1.43 | 30 | 0.008 | 57 | 0.91 | -175 |
| 500 | 0.95 | 178 | 1.03 | 23 | 0.013 | 77 | 0.93 | -179 |
| 600 | 0.95 | 173 | 0.76 | 14 | 0.019 | 78 | 0.95 | 176 |
| 700 | 0.95 | 170 | 0.56 | 7 | 0.023 | 75 | 0.96 | 173 |
| 800 | 0.96 | 166 | 0.39 | 5 | 0.025 | 76 | 0.97 | 169 |
| 900 | 0.97 | 163 | 0.33 | 9 | 0.032 | 84 | 0.97 | 166 |
| 1000 | 0.98 | 158 | 0.3 | 7 | 0.041 | 78 | 0.97 | 162 |

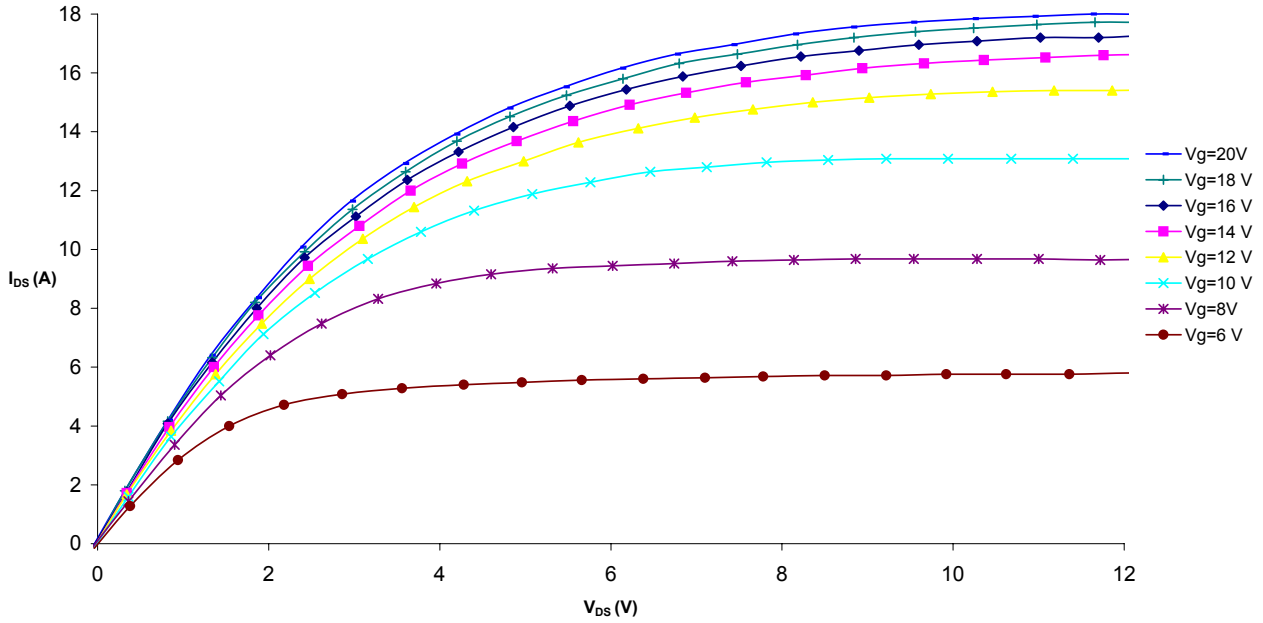


Figure 4 – Typical IV Characteristics.

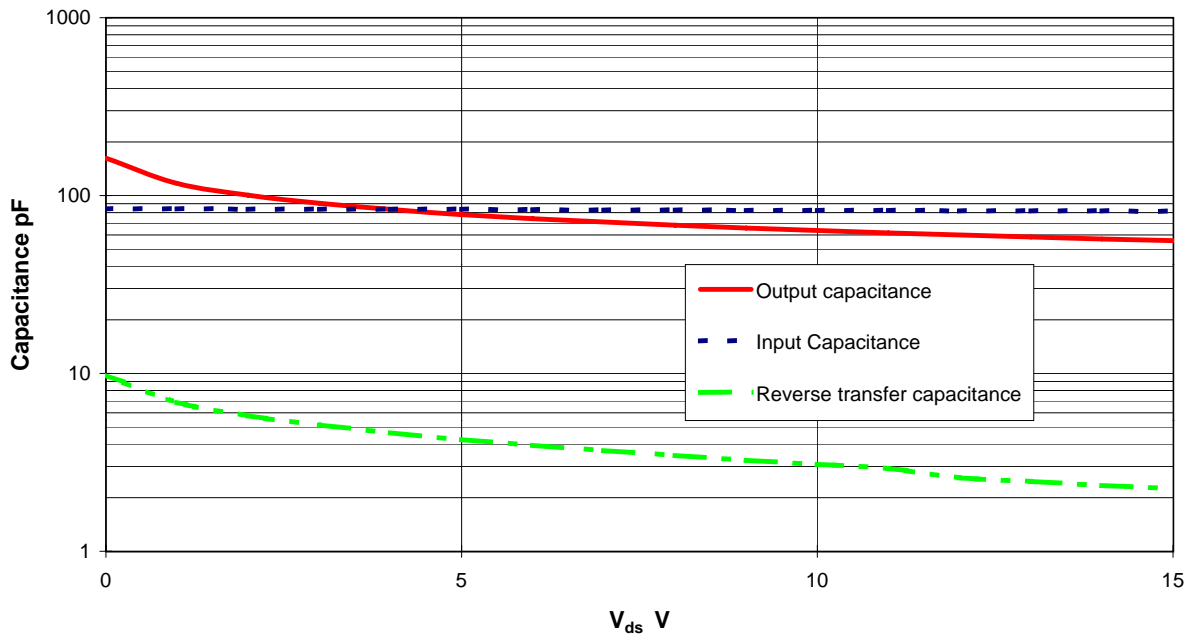
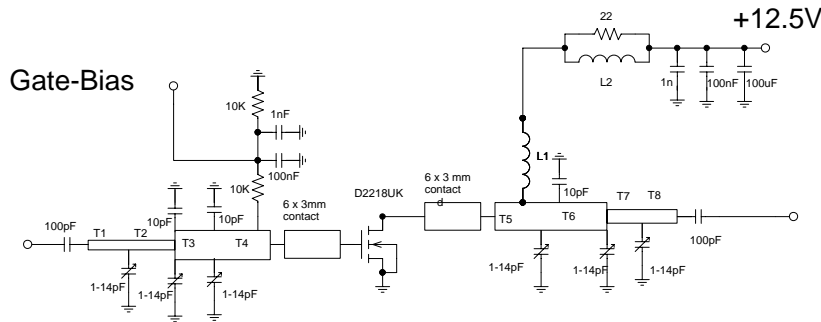


Figure 5 – Typical CV Characteristics.

Semelab Plc reserves the right to change test conditions, parameter limits and package dimensions without notice. Information furnished by Semelab is believed to be both accurate and reliable at the time of going to press. However Semelab assumes no responsibility for any errors or omissions discovered in its use. Semelab encourages customers to verify that datasheets are current before placing orders.



D2218UK 500MHz TEST FIXTURE

Substrate Taconic RF35 0.8mm, Er=3.5

T1 1.68mm wide, 21mm long

T2 1.68mm wide, 104mm long

T3 8.92mm wide, 17mm long

T4 8.92mm wide, 13.5mm long

T5 6.34mm wide, 11.5mm long

T6 6.34mm wide, 9mm long

T7 1.68mm wide, 13mm long

T8 1.68mm wide, 28mm long

L1 10 turns 0.5mm dia enamelled copper wire, 3mm i.d.

L2 1.5 turns 0.5mm dia enamelled copper wire on Siemens B62152-A7X ferrite core